## **MGN1 Series**





### **FEATURES**

- Patent protected
- Optimised output voltages designed to meet leading GaN devices requirements
- Reinforced insulation to UL62368 recognition pending
- SkVAC isolation test voltage 'Hi Pot Test'
- Ultra low isolation capacitance
- Surface mount package style
- 5V & 12V inputs
- +8V, +12V & +6V/-3V outputs
- Operation up to 105°C
- Short circuit protection
- Reverse polarity protection
- Characterised CMTI >200kV/µS
- Continuous barrier withstand voltage 1.1kV
- Characterised partial discharge performance

### **PRODUCT OVERVIEW**

The MGN1 series of DC-DC converters is ideal for powering 'high side' and 'low side' gate drive circuits for GaN in bridge circuits. A choice of output voltages allows optimum drive levels for best system efficiency. The MGN1 series is characterised for high isolation requirements commonly seen in bridge circuits used in motor drives and inverters, while the MGN1 industrial grade temperature rating and construction gives long service life and reliability.



3kVAC Isolated 1W SM GaN Gate Drive DC-DC Converters

SELECTION GUID	SELECTION GUIDE (Continued)							
Order Code <sup>1</sup>	Ripple & Noise (Typ) <sup>3</sup>	Ripple & Noise (Max) <sup>3</sup>	Efficiency (Min)	Efficiency (Typ)	Isolation Capacitance	Ĺ	MTTF2	
	mV	р-р	0/	6	pF	MIL.	Tel.	
		P P	,0		рі	kHrs		
MGN1S0508MC	20	50	58	61	2.5	2542	32674	
MGN1S0512MC	20	50	58	62.5	2.5	2263	30885	
MGN1S1208MC	20	50	62	67.5	2.5	2128	34861	
MGN1S1212MC	20	50	65	69	2.5	2484	38343	
MGN1D050603MC	20	50	58	62	2.5	1503	24882	
MGN1D120603MC	20	50	64	68.5	2.5	1696	31467	

Parameter	Conditions	Min.	Тур.	Max.	Units	
14-11	Continuous operation, 5V input types	4.5	5	5.5	v	
Voltage range	Continuous operation, 12V input types	10.8	12	13.2	v	
	MGN1S0508MC, MGN1D050603MC		120			
	MGN1S0512MC		130			
Input short circuit	MGN1S1208MC		70		mA	
current I <sub>sc</sub>	MGN1S1212MC		60		_	
	MGN1D120603MC		65			
Input reflected ripple	MGN1S0508MC, MGN1S0512MC, MGN1S1208MC, MGN1D120603MC		35		mA	
	MGN1S1212MC		30		р-р	
	MGN1D050603MC		40		1	

GENERAL CHARACTERIS	STICS				
Parameter	Conditions	Min.	Тур.	Max.	Units
Switching froquency	5V input type		150		kHz
Switching frequency	12V input type		160		K172



 Components are supplied in tape and reel packaging, please refer to package specification section. Orderable part numbers are MGN1SXXXXMC-R7/MGN1DXXXXXMC-R7 (155 pieces per reel), or MGN1SXXXXMC-R13/MGN1DXXXXXMC-R13 (620 pieces per reel).

2. Calculated using MIL-HDBK-217 FN2 and Telcordia SR-332 calculation model with nominal input voltage at full load.

3. See ripple & noise test method.

All specifications typical at T<sub>A</sub>=25°C, nominal input voltage and rated output current unless otherwise specified.

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Parameter	Conditions		Min.	Тур.	Max.	Units
Rated Power	T <sub>A</sub> =-40°C to 105°C				1	W
Minimum load			1			mA
		-3V output			-5	
Maximum output voltage <sup>1</sup>	1mA external load	6V output			6.25	v
Maximum output voltage	I mA external load	8V output			10	V
		12V output			15	
	MGN1S0508MC	MGN1S0508MC			-1	-
	MGN1S0512MC		-2		2	
	MGN1S1208MC		3		7	
Valtage Cat Daint Assurages?	MGN1S1212MC	1		5		
Voltage Set Point Accuracy <sup>2</sup>	MGN1D050603MC	OP1	-3		4	%
		0P2	-6		5	
	MGN1D120603MC	0P1	-2		5	
		0P2	16		26	
	MGN1S0508MC, MGN1S0512MC & MGN1S1212MC			1.1	1.2	
Line regulation	MGN1S1208MC			1.2	1.25	
	MGN1D050603MC	0P1		0.1	0.2	%/%
		0P2		3.2	3.5	
	MONTELOCOOMO	0P1		0.1	0.2	
	MGN1D120603MC	0P2		3.2	3.5	1

<b>ISOLATION CHAR</b>	ACTERISTICS						
Parameter		Conditions		Min.	Тур.	Max.	Units
laslation toot valte on		Production tested for 1 second		3000			VAC
Isolation test voltage		Qualification tested for 1 minute		3000			VAC
Resistance		Viso= 1000VDC		10			GΩ
Continuous barrier w	vithstand voltage	Non-safety barrier application				1100	VDC
Safety standard <sup>3</sup> UL62368-1		Reinforced	Creepage and clearance 6.5mm			250	Vrms
Salety Stallualu	0102300-1	Basic	Greepage and Clearance 6.511111			650	VDC

TEMPERATURE CHARACTE	RISTICS					
Parameter	Conditions		Min.	Тур.	Max.	Units
Specification	see derating curves		-40		105	
Storage			-40		125	
	MGN1S0508MC	1 Layer PCB		31		
	Man 130306Mic	4 Layer PCB		15		°C
	MGN1S0512MC	1 Layer PCB		34		
		4 Layer PCB		17		
	MGN1S1208MC	1 Layer PCB		27		
Product Temperature above		4 Layer PCB		15		
ambient	MONICIOIONO	1 Layer PCB		23		
	MGN1S1212MC	4 Layer PCB		10		
	MGN1D050603MC	1 Layer PCB		29		
		4 Layer PCB		15		
		1 Layer PCB		22		
		MGN1D120603MC 4 Layer PCB		12		
Cooling	Free air convection					

ABSOLUTE MAXIMUM RATINGS		
Short-circuit protection		See graphs
Input voltage V <sub>IN</sub> , MGN1X05		7V
Input voltage V <sub>IN</sub> , MGN1X12		15V
Deverse pelerity	MGN1X05	5.5V
Reverse polarity	MGN1X12	13.2V

1. Most gate drive circuits will have at least 1mA of standby current, if this is not the case an external bleed resistor may be necessary.

T<sub>A</sub>=25°C, nominal input voltage and 75% load.
UL62368-1 recognition is currently pending.

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## **MGN1 Series**

### 3kVAC Isolated 1W SM GaN Gate Drive DC-DC Converters

#### **TECHNICAL NOTES**

#### **ISOLATION VOLTAGE**

'Hi Pot Test', 'Flash Tested', 'Withstand Voltage', 'Proof Voltage', 'Dielectric Withstand Voltage' & 'Isolation Test Voltage' are all terms that relate to the same thing, a test voltage, applied for a specified time, across a component designed to provide electrical isolation, to verify the integrity of that isolation.

Murata Power Solutions MGN1 series of DC-DC converters are all 100% production tested at 3kVAC for 1 second and have been qualification tested at 3kVAC for 1 minute.

A question commonly asked is, "What is the continuous voltage that can be applied across the part in normal operation?"

When the insulation in the MGN1 series is not used as a safety barrier, i.e. provides functional isolation only, continuous or switched voltages across the barrier up to 1.1kV are sustainable. Long term reliability testing at these voltages continues. Peak Inception voltages measured were in excess of 1.1kV when testing for partial discharge in accordance with IEC 60270. Please contact Murata for further information.

The MGN1 series is pending recognition by Underwriters Laboratory to 250VAC Reinforced Insulation, please see safety approval section below.

#### **REPEATED HIGH-VOLTAGE ISOLATION TESTING**

It is well known that repeated high-voltage isolation testing of a barrier component can actually degrade isolation capability, to a lesser or greater degree depending on materials, construction and environment. We therefore strongly advise against repeated high voltage isolation testing, but if it is absolutely required, that the voltage be reduced by 20% from specified test voltage.

#### SAFETY APPROVAL

#### UL62368-1

The MGN1 series is pending recognition by Underwriters Laboratory (UL) to UL62368-1 for reinforced insulation to a working voltage of 250Vrms and for basic insulation to a working voltage of 650Vrms.

Creepage and clearance 6.5mm. Working altitude OVC II 5000m

#### FUSING

The MGN1 Series of converters are not internally fused so to meet the requirements of UL an anti-surge input line fuse should always be used with ratings as defined below.

Input Voltage, 5V 0.5A Input Voltage, 12V 0.25A All fuses should be Anti-Surge and UL rated.

#### **RoHS COMPLIANCE AND MSL INFORMATION**



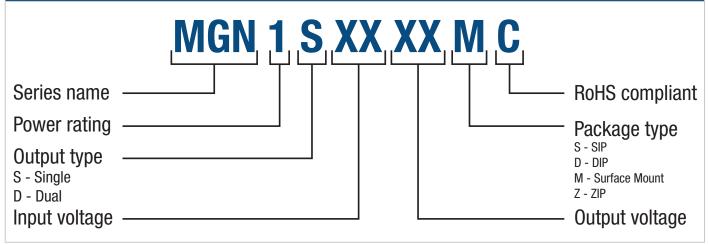
This series is compatible with Pb-Free soldering systems and is also backward compatible with Sn/Pb soldering systems. The series can be soldered in accordance with J-STD-020. Please refer to <u>application notes</u> for further information. This series have a classification temperature of 260°C and moisture sensitivity level 2. The termination finish on this product is Gold with plating thickness 0.12 microns.

## **MGN1 Series**

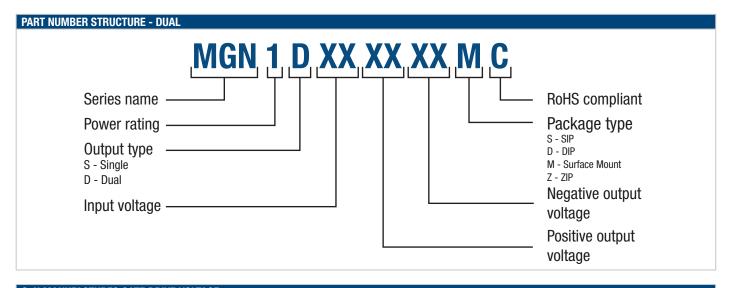
3kVAC Isolated 1W SM GaN Gate Drive DC-DC Converters

ENVIRONMENTAL	ALIDATION TESTING	
The following tests ha	ve been conducted on this product s	eries, please contact Murata if further information about the tests is required.
Test	Standard	Condition
Temperature cycling	JEDEC JESD22-A104	500 cycles in a dual zone chamber from -40 (+5/-10)°C to 105 (+10/-5)°C. 15mins dwell at each (inclusive of ramps). 2 cycles per hour
HAST (unbiased)	JEDEC JESD22-A118	130±2°C, 85±5% R.H. for 96 (+2/-0) hours
Storage life (high temperature)	JEDEC JESD22-A103, Condition A	125°C +10/-0°C for $\geq$ 1000 hours
Storage life (low temperature)	JEDEC JESD22-A119	-40°C -10/+0°C for ≥1000 hours
MSL	IPC/JEDEC J-STD-020	Bake samples at 125 +5/-0°C for 24hours minimum before conditioning in the temperature/humidity chamber for 168 hours at $85^{\circ}$ C/60%RH and Pb Free JEDEC Max profile conditioning with electrical testing, co-planarity, visual inspection before and after.
Vibration	JEDEC JESD22-B103	20Hz to 2 kHz to 20Hz (logarithmic variation) in >4 minutes, 4 times in each orientation (i.e. 12times), 50G ( $\pm$ 10%) peak acceleration. Sinusoidal Vibration.
Shock	JEDEC JESD22 B110	5 pulses half sine pulses of 0.5msec ( $\pm$ 15%)duration, 1500g ( $\pm$ 10%) peak acceleration. This equates to free state test level B in JESD22-B110 which states an Equivalent drop height of 112cm and a Velocity change 468cm/s ( $\pm$ 10%).
Solvent cleaning	Resistance to cleaning agents.	Solvent – Novec 71IPA & Topklean EL-20A. Pulsed ultrasonic immersion 45°C - 65°C

#### PART NUMBER STRUCTURE - SINGLE



## **MGN1 Series**



GaN MANUFACTURES GATE DRIVE VC	Gan MANUFACTURES GATE DRIVE VOLTAGE				
GaN manufactures	Gate voltage	MGN1 part number			
GaN Systems	+6V/-3V	MGN1D050603MC & MGN1D120603MC			
Infineon	8V	MGN1D0508MC & MGN1D1208MC			
Texas Instruments	12V	MGN1D0512MC & MGN1D1212MC			
GanPower international	+6V/-3V	MGN1D050603MC & MGN1D120603MC			
Nexperia	12V	MGN1D0512MC & MGN1D1212MC			
Navitas	12V	MGN1D0512MC & MGN1D1212MC			
Transphorm	12V	MGN1D0512MC & MGN1D1212MC			

## **MGN1 Series**

3kVAC Isolated 1W SM GaN Gate Drive DC-DC Converters

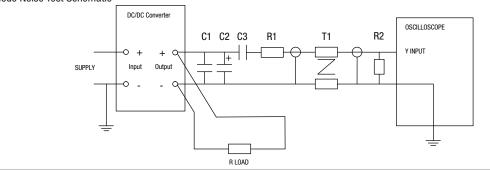
#### CHARACTERISATION TEST METHODS

#### Ripple & Noise Characterisation Method

Ripple and noise measurements are performed with the following test configuration.

C1	1µF X7R multilayer ceramic capacitor, voltage rating to be a minimum of 3 times the output voltage of the DC-DC converter
C2	$10\mu$ F tantalum capacitor, voltage rating to be a minimum of 1.5 times the output voltage of the DC-DC converter with an ESR of less than $100m\Omega$ at $100 \text{ kHz}$
C3	100nF multilayer ceramic capacitor, general purpose
R1	450Ω resistor, carbon film, $\pm$ 1% tolerance
R2	50Ω BNC termination
T1	3T of the coax cable through a ferrite toroid
RLOAD	Resistive load to the maximum power rating of the DC-DC converter. Connections should be made via twisted wires
Measured va	lues are multiplied by 10 to obtain the specified values.

**Differential Mode Noise Test Schematic** 



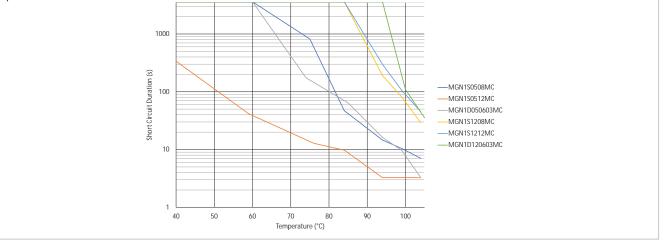
#### APPLICATION NOTES

#### Gate Drive Applications Advisory Note

For general guidance for product usage in gate drive applications please refer to "gate drive application notes".

#### Short Circuit Performance

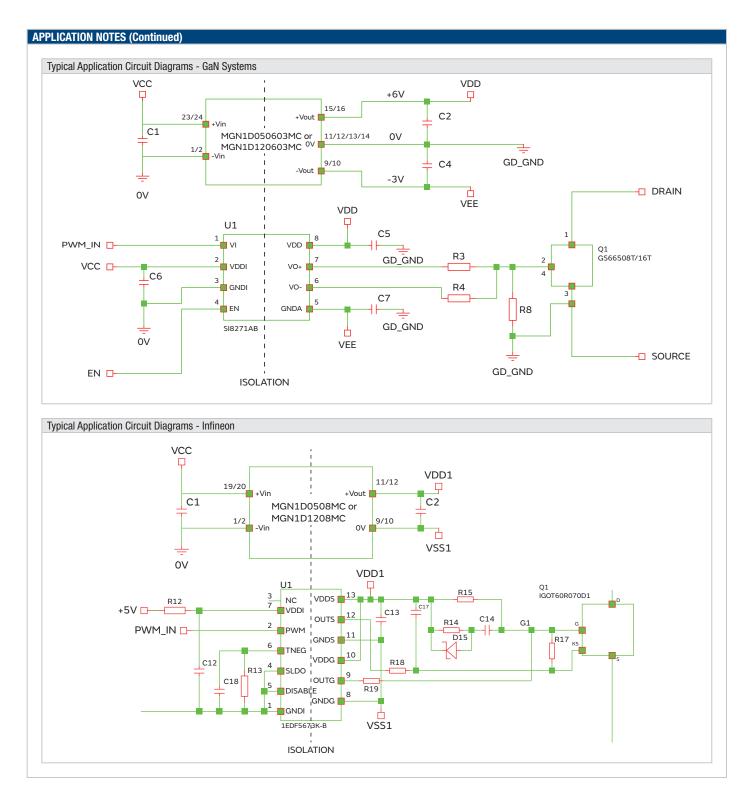
Below an ambient temperature of 40°C, the MGN1 short circuit protection is continuous. Above 40°C, short circuit duration time is reduced as shown in the following graph:



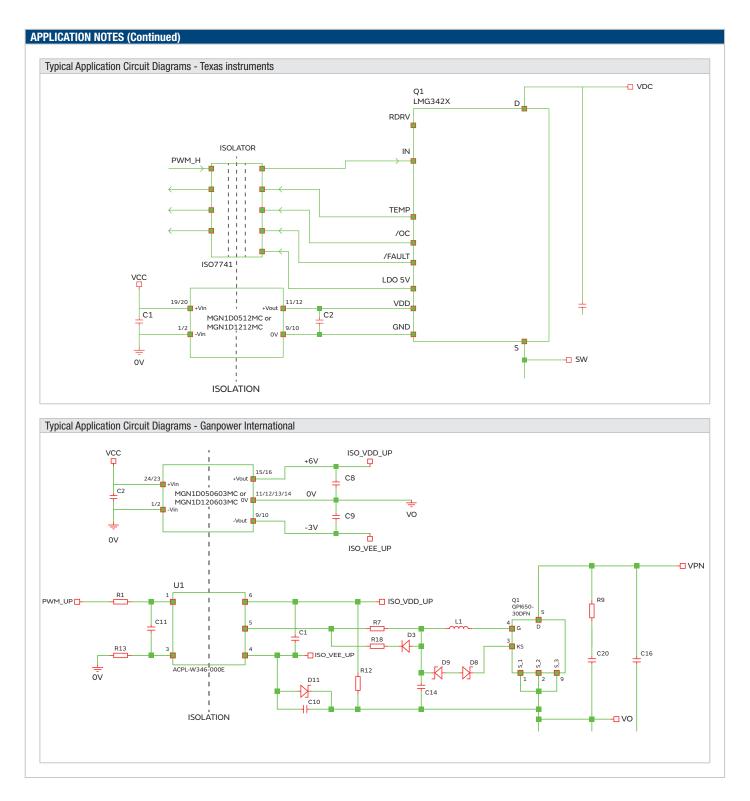
#### Typical Application Circuit Diagrams

The following circuit diagrams are intended to provide guidance on how to connect the MGN1 series to GaN drivers for GaN devices. Please refer to GaN manufactures datasheets for full application circuits.

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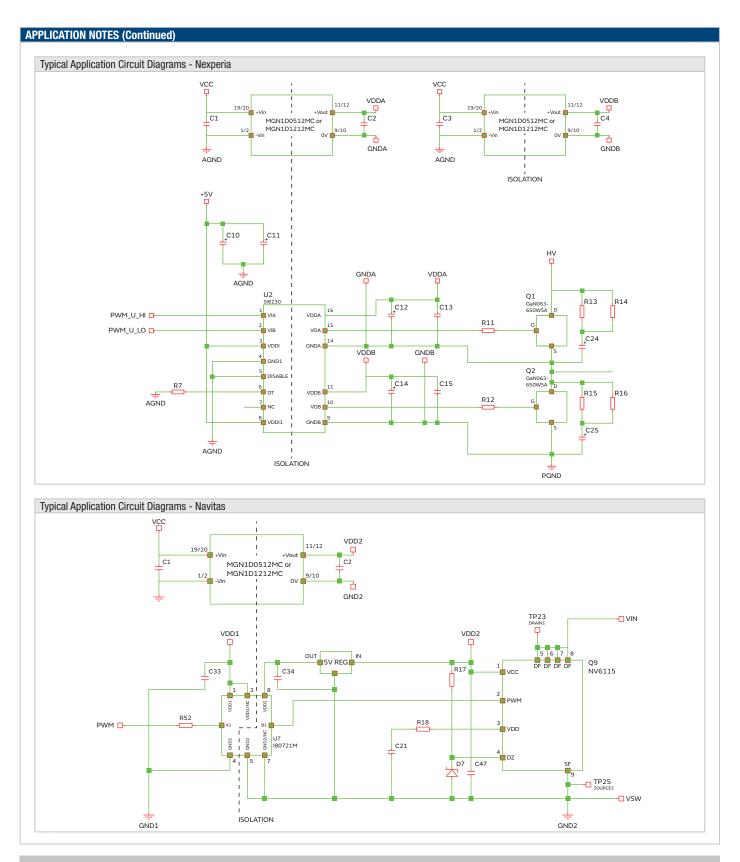


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3kVAC Isolated 1W SM GaN Gate Drive DC-DC Converters

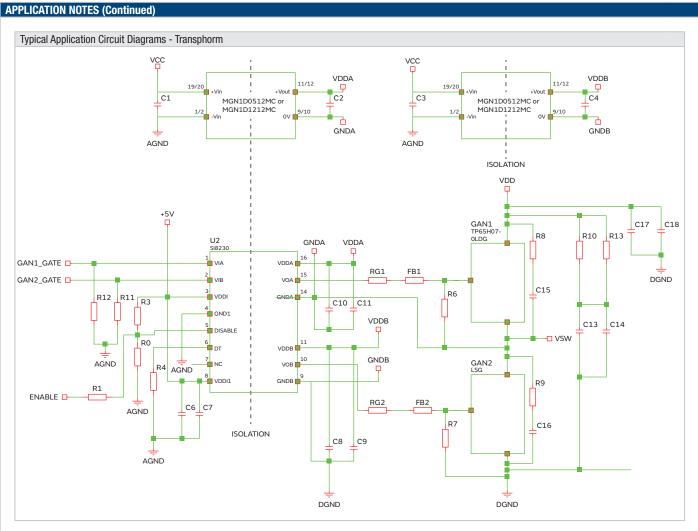


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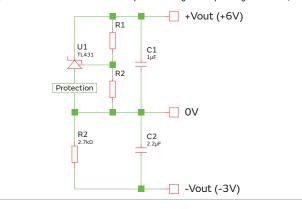
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#### **Dual Output Configuration**

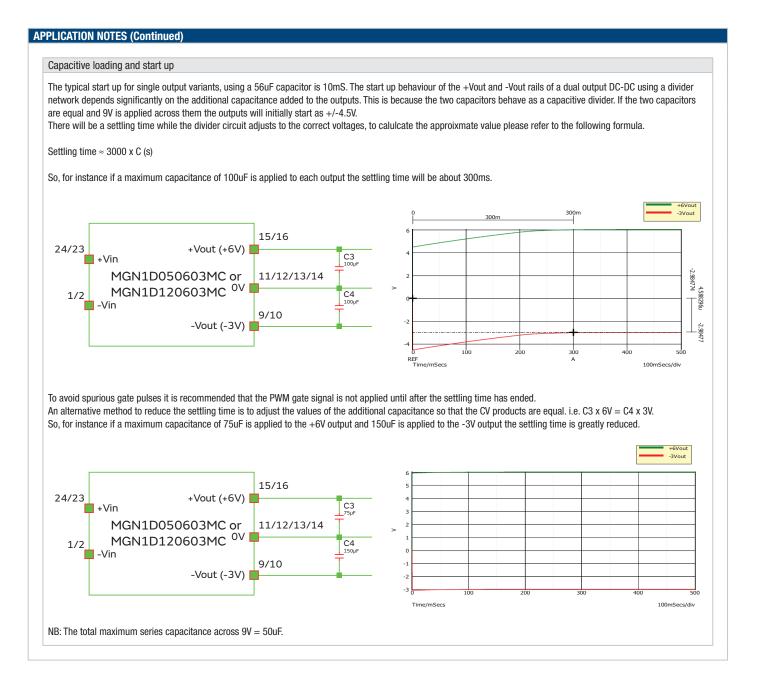
The MGN1D050603MC and MGN1D120603MC are dual output DC-DC converters specifically designed for gate drive applications and are not suitable for general purpose dual output use. However, each can be used as a general purpose single 9V output converter, by loading from +Vout to -Vout.

The MGN1D050603MC and MGN1D120603MC provide a dual output by using a reference IC and resistor divider network circuit with patented short circuit protection. This is important to maintain an accurate 6V to the gate of the GaN device over the temperature range and operating conditions, something a Zener diode cannot guarantee.



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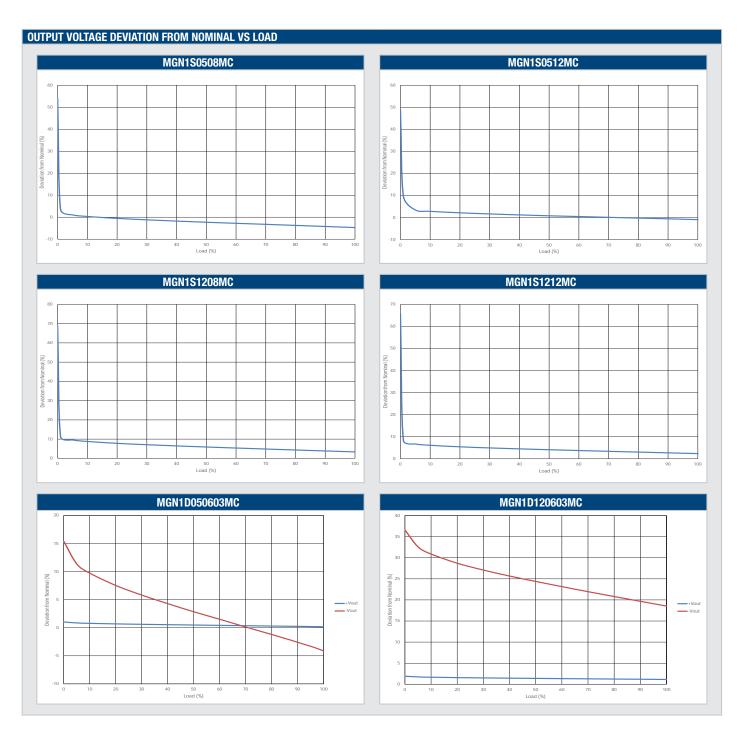
## **MGN1 Series**



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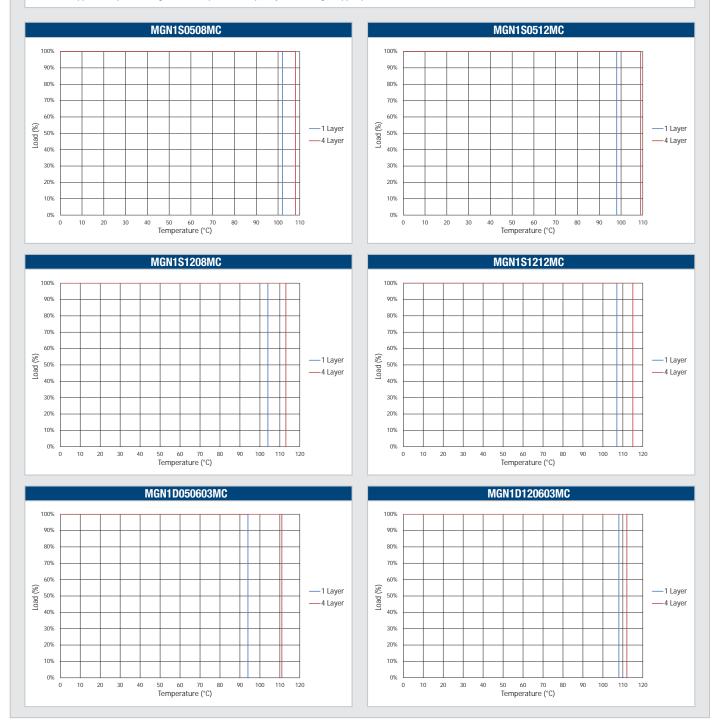


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#### **TEMPERATURE DERATING**

The MGN1 series has been designed to minimise the thermal impedance when mounted onto a customers application PCB by using multiple surface mount pads for each connection. All thermal measurements were carried out in still air using a test pcb designed in accordance with standard JESD51-9 (Test Boards for Area Array Surface Mount Package Thermal Measurements). A single layer and a 4 layer have been used and this demonstrates that a higher operating temperature can be achieved when the customers application pcb is designed to incorporate multiple layers and large copper planes. Please contact Murata for further information.

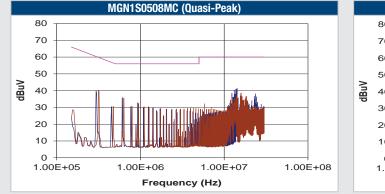


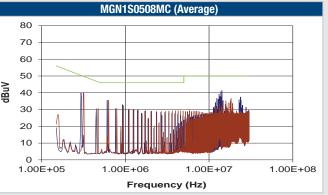
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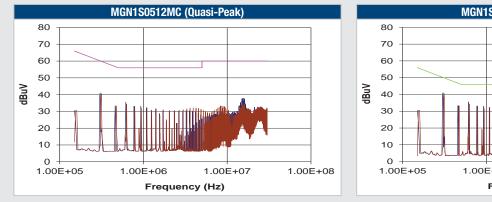
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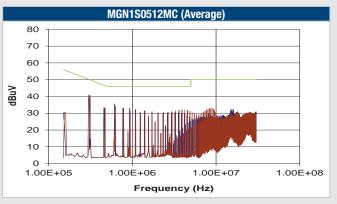
3kVAC Isolated 1W SM GaN Gate Drive DC-DC Converters

#### EMC FILTERING AND SPECTRA FILTERING The following filter circuit and filter table shows the input filters typically required to meet EN55022 Quasi-PeakCurve A or B. Cd DC С Power Load Rd Source DC Inductor Capacitor Resistor Capacitor L, µH SMD C, µF SMD Rd, $\Omega$ Cd, µF MGN1S0508MC 22 29223C 10 GRM31CR61E106KA12L 3 10 MGN1S0512MC 22 29223C 10 GRM31CR61E106KA12L 3 10 MGN1S1208MC 10 34103C 10 GRM31CR61E106KA12L 3 10 MGN1S1212MC 10 34103C 10 GRM31CR61E106KA12L 3 10 MGN1S050603MC 22 29223C 10 GRM31CR61E106KA12L 3 10 MGN1S120603MC GRM31CR61E106KA12L 10 34103C 10 3 10



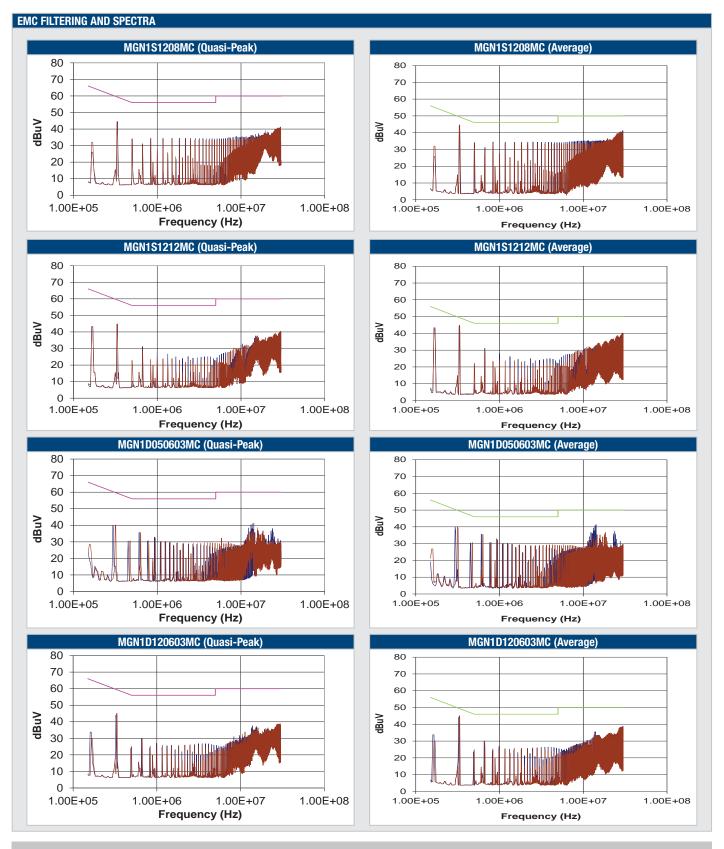






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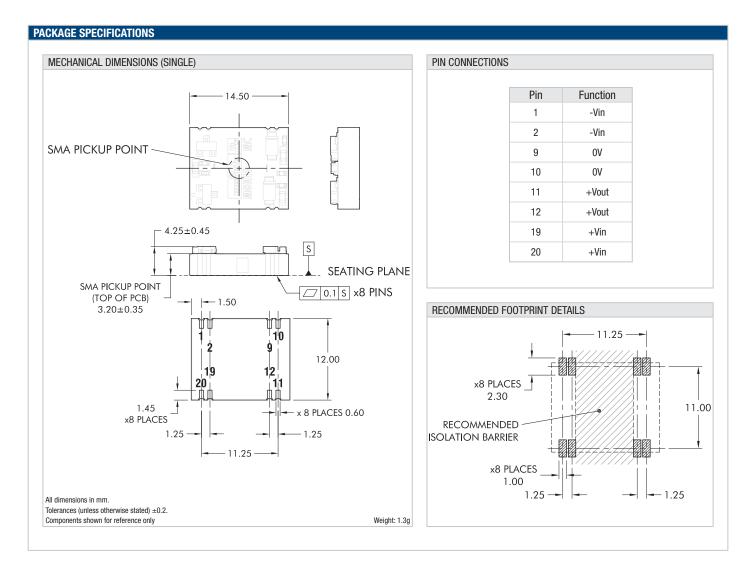
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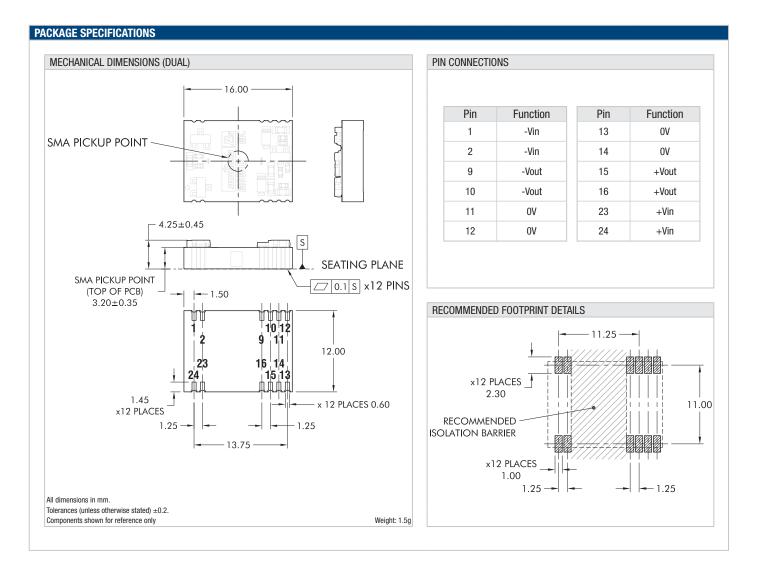
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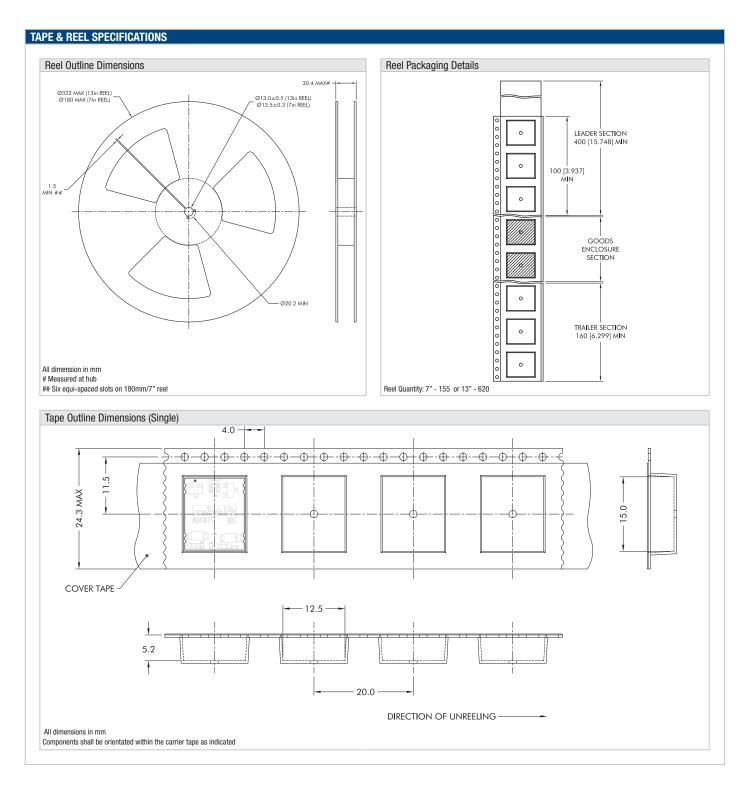
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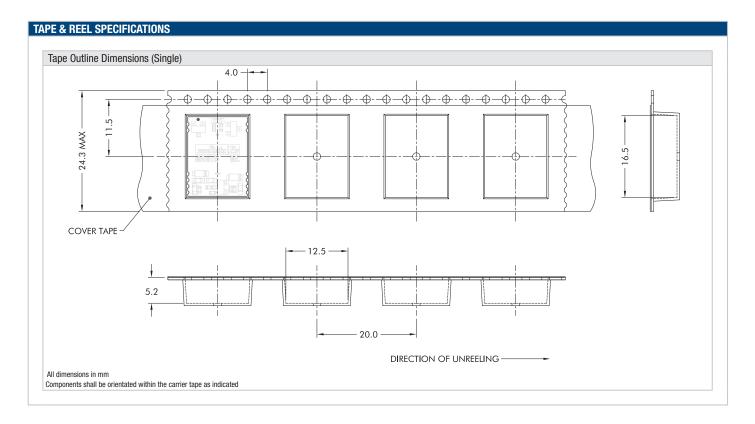
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- Aerospace equipment
- Undersea equipment
- Power plant control equipment
- Medical equipment
- Transportation equipment ( automobiles, trains, ships, etc.)
- Traffic signal equipment
- Disaster prevention / crime prevention equipment
- Data Processing equipment

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